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### **Electronic Transport Investigations of Reduced Graphene Oxide Sheet<sup>1</sup>**

DAEHA JOUNG, Nanosceince Technology Center and Department of Physics, University of Central Florida

Reduced graphene oxide (RGO) sheet, a chemically functionalized atomically thin carbon sheet, provides a convenient pathway for producing large quantities of graphene via solution processing. The easy processibility of RGO sheet and its composites offer interesting electronic, chemical and mechanical properties that are currently being explored for advanced electronics and energy based materials. However, a clear understanding of electron transport properties of RGO sheet is lacking which is of great significance for determining its potential application. In this talk, we will present fabrication of high-yield solution based graphene field effects transistor (FET) using AC dielectrophoresis (DEP) and investigate the detailed electronic transport properties of the fabricated devices. The majority of the devices show ambipolar FET properties at room temperature. However, the mobility values are found to be lower than pristine graphene due to a large amount of residual defects in RGO sheets. We calculated the density of these defects by analyzing the low temperature (300 to 77K) charge transport data using space charge limited conduction (SCLC) with exponential trap distribution. At very low temperature (down to 4.2 K), we observe Coulomb blockade (CB) and Efros-Shklovskii variable range hopping (ES-VRH) conduction in RGO implying that RGO can be considered as a graphene quantum dots array (GQD), where graphene domains act like QDs while oxidized domains behave like tunnel barriers between QDs. This was further confirmed by studying RGO sheets of varying carbon  $sp^2$  fraction from 55%-80% and found that both the localization length and CB can be tuned. From the localization length and using two band Kane model, we estimate tunable band gap of RGO sheets with varying carbon  $sp^2$  fraction.

<sup>1</sup>In collaboration with Saiful I. Khondaker, Nanosceince Technology Center, Department of Physics, and School of Electrical Engineering and Computer Science, University of Central Florida